

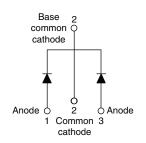


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Schottky Rectifier, 2 x 30 A

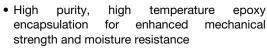




PRODUCT SUMMARY					
Package	TO-220AB				
I _{F(AV)}	2 x 30 A				
V_R	35 V, 40 V, 45 V				
V _F at I _F	0.57 V				
I _{RM} max.	40 mA at 125 °C				
T _J max.	175 °C				
Diode variation	Common cathode				
E _{AS}	27 mJ				

FEATURES

- 175 °C T_J operation
- Low forward voltage drop
- High frequency operation





- Guard ring for enhanced ruggedness and long term reliability
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified according to JEDEC-JESD47
- Halogen-free according to IEC 61249-2-21 definition (-N3 only)

DESCRIPTION

This center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	CHARACTERISTICS VALUES UNITS								
I _{F(AV)}	Rectangular waveform (per device)	60	Α						
V _{RRM}		35 to 45	V						
I _{FRM}	T _C = 142 °C (per leg)	60	^						
I _{FSM}	t _p = 5 μs sine	2600	A						
V _F	30 A _{pk} , T _J = 125 °C	0.57	V						
TJ	Range	- 65 to 175	°C						

VOLTAGE RATINGS										
PARAMETER	SYMBOL	VS- 61CTQ035PbF	VS- 61CTQ035-N3	VS- 61CTQ040PbF	VS- 61CTQ040-N3	VS- 61CTQ045PbF	VS- 61CTQ045-N3	UNITS		
Maximum DC reverse voltage	V_{R}									
Maximum working peak reverse voltage	V _{RWM}	35	35	40	40	45	45	V		

ABSOLUTE MAXIMUM RATINGS								
PARAMETER		SYMBOL	TEST CONDITIONS		VALUES	UNITS		
Maximum average per leg forward current per device			T = 140 °C rotod V	140.00				
		I _{F(AV)}	T _C = 142 °C, rated V _R		60	A		
Peak repetitive forward current per leg		I _{FRM}	Rated V _R , square wave, 20 kHz, T _C = 142 °C		60			
Maximum peak one cycle non-repetitive surge current per leg		l=	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated	2600			
		I _{FSM}	10 ms sine or 6 ms rect. pulse	V _{RRM} applied	350			
Non-repetitive avalanche energy per leg		E _{AS}	T _J = 25 °C, I _{AS} = 4 A, L = 3.4 mH		27	mJ		
Repetitive avalanche current per leg		I _{AR}	Current decaying linearly to zero in 1 μs Frequency limited by T _J maximum V _A = 1.5 x V _B typical		4	Α		

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VS-61CTQ...PbF Series, VS-61CTQ...-N3 Series

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ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CO	NDITIONS	TYP.	MAX.	UNITS		
		30 A	T _{.1} = 25 °C	0.57	0.61			
Maximum forward voltage drop	V _{FM} ⁽¹⁾	60 A	11 = 23 0	0.72	0.76	V		
		30 A	T 105 00	0.53	0.57			
		60 A	T _J = 125 °C	0.70	0.74			
Maximum instantaneous reverse current	I _{RM}	T _J = 25 °C	Rated DC voltage	0.06	1	mA		
waximum instantaneous reverse current		T _J = 125 °C	hated DC voltage	21	40	IIIA		
Maximum junction capacitance	C _T	V _R = 5 V _{DC} (test signal range 100 kHz to 1 MHz) 25 °C		19	000	pF		
Typical series inductance	L _S	Measured from top of terminal to mounting plane		8	.0	nΗ		
Maximum voltage rate of change	dV/dt	Rated V _R	10	000	V/µs			

Note

 $^{^{(1)}\,}$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum junction and storage temperature range	T _J , T _{Stg}		- 65 to 175	°C				
Maximum thermal resistance, junction to case per leg	R _{thJC}	DC operation	1.2	°C/W				
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth and greased	0.50	0/ VV				
Approximate weight			2	g				
Approximate weight			0.07	OZ.				
Mounting torque minimum		Non-lubricated threads	6 (5)	kgf · cm				
Mounting torque maximum		Non-lubricated tirreads	12 (10)	(lbf ⋅ in)				
			61CTQ035					
Marking device		Case style TO-220AB	61CTQ040					
			61CT	Q045				

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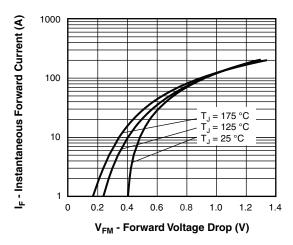


Fig. 1 - Maximum Forward Voltage Drop Characteristics

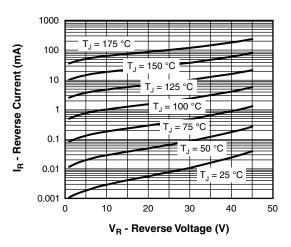


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

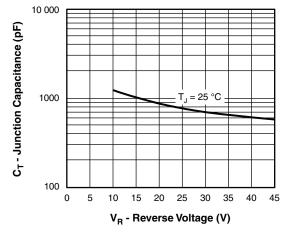


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

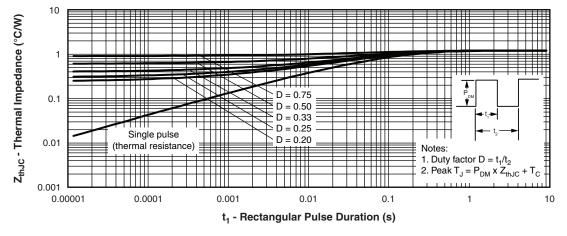


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics



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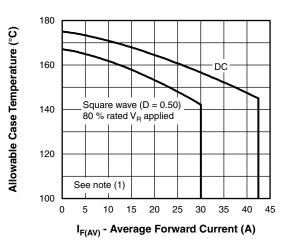


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

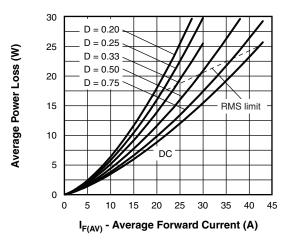


Fig. 6 - Forward Power Loss Characteristics

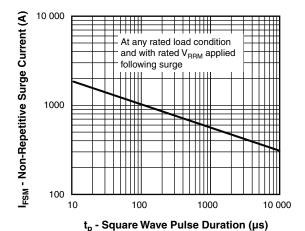


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

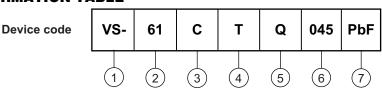
Note

 $\begin{array}{l} \text{(1)} \ \ \text{Formula used:} \ T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}; \\ Pd = \text{Forward power loss} = I_{F(AV)} \times V_{FM} \ \text{at} \ (I_{F(AV)}/D) \ \text{(see fig. 6)}; \\ Pd_{REV} = \text{Inverse power loss} = V_{R1} \times I_R \ \text{(1 - D)}; \ I_R \ \text{at} \ V_{R1} = 80 \ \% \ \text{rated} \ V_R \end{aligned}$

VS-61CTQ...PbF Series, VS-61CTQ...-N3 Series

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ORDERING INFORMATION TABLE



- 1 Vishay Semiconductors product
- 2 Current rating (60 = 60 A)
- Circuit configuration
 C = Common cathode
- Package T = TO-220
- 5 Schottky "Q" series
- Schottky "Q" series 035 = 35 V

 Voltage ratings 040 = 40 V

 Environmental digit
 - PbF = Lead (Pb)-free and RoHS compliant
 - -N3 = Halogen-free, RoHS compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-61CTQ035PbF	50	1000	Antistatic plastic tube					
VS-61CTQ035-N3	50	1000	Antistatic plastic tube					
VS-61CTQ040PbF	50	1000	Antistatic plastic tube					
VS-61CTQ040-N3	50	1000	Antistatic plastic tube					
VS-61CTQ045PbF	50	1000	Antistatic plastic tube					
VS-61CTQ045-N3	50	1000	Antistatic plastic tube					

LINKS TO RELATED DOCUMENTS					
Dimensions <u>www.vishay.com/doc?95222</u>					
Dort marking information	TO-220AB PbF	www.vishay.com/doc?95225			
Part marking information	TO-220AB -N3	www.vishay.com/doc?95028			



Vishay Semiconductors

TO-220AB

DIMENSIONS in millimeters and inches



Lead assignments

Diodes

- 1. Anode/open
- 2. Cathode
- 3. Anode

Conforms to JEDEC outline TO-220AB

SYMBOL	MILLIN	IETERS	INC	NOTES	
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.56	2.92	0.101	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.25	0.585	0.600	3
D1	8.38	9.02	0.330	0.355	
D2	11.68	12.88	0.460	0.507	6

SYMBOL	MILLIM	IETERS	INC	HES	NOTES
STIMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
E	10.11	10.51	0.398	0.414	3, 6
E1	6.86	8.89	0.270	0.350	6
E2	-	0.76	-	0.030	7
е	2.41	2.67	0.095	0.105	
e1	4.88	5.28	0.192	0.208	
H1	6.09	6.48	0.240	0.255	6, 7
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
ØΡ	3.54	3.73	0.139	0.147	
Q	2.60	3.00	0.102	0.118	
θ	90° t	o 93°	90° t	o 93°	
		•	•	•	

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1
- (7) Dimensions E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC TO-220, except A2 (maximum) and D2 (minimum) where dimensions are derived from the actual package outline

Lead tip



Legal Disclaimer Notice

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